NSN 5961-01-229-1463

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-229-1463 **Inclosure Material:** Glass and metal **Overall Length:** 0.370 inches **Terminal Length:** 1.100 inches **Overall Diameter:** 0.200 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-13 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.8 working peak reverse voltage **Current Rating Per Characteristic:** 5.00 microamperes reverse current, dc **Power Rating Per Characteristic:** 5.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No